

# NB3L553

## 2.5 V / 3.3 V / 5.0 V 1:4 Clock Fanout Buffer

### Description

The NB3L553 is a low skew 1-to 4 clock fanout buffer, designed for clock distribution in mind. The NB3L553 specifically guarantees low output-to-output skew. Optimal design, layout and processing minimize skew within a device and from device to device.

### Features

- Input/Output Clock Frequency up to 200 MHz
- Low Skew Outputs (35 ps), Typical
- RMS Phase Jitter (12 kHz – 20 MHz): 29 fs (Typical)
- Output goes to Three-State Mode via OE
- Operating Range:  $V_{DD} = 2.375\text{ V}$  to  $5.25\text{ V}$
- 5 V Tolerant Input Clock  $I_{CLK}$
- Ideal for Networking Clocks
- Packaged in 8-pin SOIC
- Industrial Temperature Range
- These are Pb-Free Devices

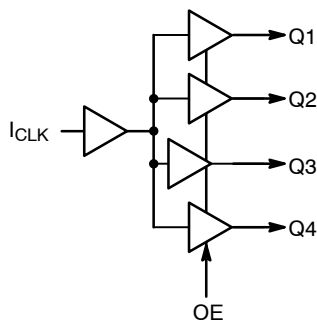


Figure 1. Block Diagram



**ON Semiconductor®**

<http://onsemi.com>

### MARKING DIAGRAMS\*



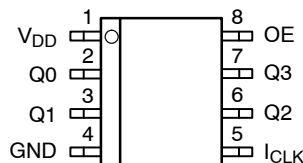
3L553 = Specific Device Code  
A = Assembly Location  
L = Wafer Lot  
Y = Year  
W = Work Week  
▪ = Pb-Free Package



6P = Specific Device Code  
M = Date Code  
▪ = Pb-Free Package  
(Note: Microdot may be in either location)

\*For additional marking information, refer to Application Note AND8002/D.

### PINOUT DIAGRAM



### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
NB3L553DG	SOIC-8 (Pb-Free)	98 Units/Rail
NB3L553DR2G	SOIC-8 (Pb-Free)	2500/Tape & Reel
NB3L553MNR4G*	DFN-8 (Pb-Free)	1000/Tape & Reel

\*Contact Sales Representative

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

## NB3L553

**Table 1. OE, OUTPUT ENABLE FUNCTION**

OE	Function
0	Disable
1	Enable

**Table 2. PIN DESCRIPTION**

Pin #	Name	Type	Description
1	V <sub>DD</sub>	Power	Positive supply voltage (2.375 V to 5.25 V)
2	Q0	(LV)CMOS/(LV)TTL Output	Clock Output 0
3	Q1	(LV)CMOS/(LV)TTL Output	Clock Output 1
4	GND	Power	Negative supply voltage; Connect to ground, 0 V
5	I <sub>CLK</sub>	(LV)CMOS Input	Clock Input. 5.0 V tolerant
6	Q2	(LV)CMOS/(LV)TTL Output	Clock Output 2
7	Q3	(LV)CMOS/(LV)TTL Output	Clock Output 3
8	OE	(LV)TTL Input	V <sub>DD</sub> for normal operation. Pin has no internal pullup or pull down resistor for open condition default. Use from 1 to 10 kOhms external resistor to force an open condition default state.
–	EP	Thermal Exposed Pad	(DFN8 only) Thermal exposed pad must be connected to a sufficient thermal conduit. Electrically connect to the most negative supply (GND) or leave unconnected, floating open.

**Table 3. MAXIMUM RATINGS**

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V <sub>DD</sub>	Positive Power Supply	GND = 0 V	–	6.0	V
V <sub>I</sub>	Input Voltage	OE I <sub>CLK</sub>	GND = 0 V and V <sub>DD</sub> = 2.375 V to 5.25 V	GND – 0.5 ≤ V <sub>I</sub> ≤ V <sub>DD</sub> + 0.5 GND – 0.5 ≤ V <sub>I</sub> ≤ 5.75	V
T <sub>A</sub>	Operating Temperature Range, Industrial	–	–	≥ –40 to ≤ +85	°C
T <sub>stg</sub>	Storage Temperature Range	–	–	–65 to +150	°C
θ <sub>JA</sub>	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	SOIC–8	190 130	°C/W °C/W
θ <sub>JC</sub>	Thermal Resistance (Junction-to-Case)	(Note 1)	SOIC–8	41 to 44	°C/W
θ <sub>JA</sub>	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	DFN8 DFN8	129 84	°C/W °C/W
θ <sub>JC</sub>	Thermal Resistance (Junction-to-Case)	(Note 1)	DFN8	35 to 40	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. JEDEC standard multilayer board – 2S2P (2 signal, 2 power)

**Table 4. ATTRIBUTES**

Characteristic	Value
ESD Protection Human Body Model Machine Model Charged Device Model	> 2 kV > 150 V > TBD kV
Moisture Sensitivity, Indefinite Time Out of Drypack (Note 2)	Level 1
Flammability Rating Oxygen Index: 28 to 34	UL–94 code V–0 @ 0.125 in
Transistor Count	531 Devices
Meets or Exceeds JEDEC Standard EIA/JESD78 IC Latchup Test	

2. For additional Moisture Sensitivity information, refer to Application Note AND8003/D.

# NB3L553

**Table 5. DC CHARACTERISTICS** ( $V_{DD} = 2.375 \text{ V to } 2.625 \text{ V}$ ,  $GND = 0 \text{ V}$ ,  $T_A = -40^\circ\text{C to } +85^\circ\text{C}$ ) (Note 3)

Symbol	Characteristic	Min	Typ	Max	Unit
$I_{DD}$	Power Supply Current @ 135 MHz, No Load	–	25	30	mA
$V_{OH}$	Output HIGH Voltage – $I_{OH} = -16 \text{ mA}$	1.7	–	–	V
$V_{OL}$	Output LOW Voltage – $I_{OL} = 16 \text{ mA}$	–	–	0.4	V
$V_{IH}, I_{CLK}$	Input HIGH Voltage, $I_{CLK}$	$(V_{DD} \div 2) + 0.5$	–	5.0	V
$V_{IL}, I_{CLK}$	Input LOW Voltage, $I_{CLK}$	–	–	$(V_{DD} \div 2) - 0.5$	V
$V_{IH}, OE$	Input HIGH Voltage, OE	1.8	–	$V_{DD}$	V
$V_{IL}, OE$	Input LOW Voltage, OE	–	–	0.7	V
ZO	Nominal Output Impedance	–	20	–	$\Omega$
CIN	Input Capacitance, $I_{CLK}$ , OE	–	5.0	–	pF
IOS	Short Circuit Current	–	$\pm 28$	–	mA

**DC CHARACTERISTICS** ( $V_{DD} = 3.15 \text{ V to } 3.45 \text{ V}$ ,  $GND = 0 \text{ V}$ ,  $T_A = -40^\circ\text{C to } +85^\circ\text{C}$ ) (Note 3)

Symbol	Characteristic	Min	Typ	Max	Unit
$I_{DD}$	Power Supply Current @ 135 MHz, No Load	–	35	40	mA
$V_{OH}$	Output HIGH Voltage – $I_{OH} = -25 \text{ mA}$	2.4	–	–	V
$V_{OL}$	Output LOW Voltage – $I_{OL} = 25 \text{ mA}$	–	–	0.4	V
$V_{OH}$	Output HIGH Voltage – $I_{OH} = -12 \text{ mA}$ (CMOS level)	$V_{DD} - 0.4$	–	–	V
$V_{IH}, I_{CLK}$	Input HIGH Voltage, $I_{CLK}$	$(V_{DD} \div 2) + 0.7$	–	5.0	V
$V_{IL}, I_{CLK}$	Input LOW Voltage, $I_{CLK}$	–	–	$(V_{DD} \div 2) - 0.7$	V
$V_{IH}, OE$	Input HIGH Voltage, OE	2.0	–	$V_{DD}$	V
$V_{IL}, OE$	Input LOW Voltage, OE	0	–	0.8	V
ZO	Nominal Output Impedance	–	20	–	$\Omega$
CIN	Input Capacitance, OE	–	5.0	–	pF
IOS	Short Circuit Current	–	$\pm 50$	–	mA

**DC CHARACTERISTICS** ( $V_{DD} = 4.75 \text{ V to } 5.25 \text{ V}$ ,  $GND = 0 \text{ V}$ ,  $T_A = -40^\circ\text{C to } +85^\circ\text{C}$ ) (Note 3)

Symbol	Characteristic	Min	Typ	Max	Unit
$I_{DD}$	Power Supply Current @ 135 MHz, – No Load	–	45	85	mA
$V_{OH}$	Output HIGH Voltage – $I_{OH} = -35 \text{ mA}$	2.4	–	–	V
$V_{OL}$	Output LOW Voltage – $I_{OL} = 35 \text{ mA}$	–	–	0.4	V
$V_{OH}$	Output HIGH Voltage – $I_{OH} = -12 \text{ mA}$ (CMOS level)	$V_{DD} - 0.4$	–	–	V
$V_{IH}, I_{CLK}$	Input HIGH Voltage, $I_{CLK}$	$(V_{DD} \div 2) + 1$	–	5.0	V
$V_{IL}, I_{CLK}$	Input LOW Voltage, $I_{CLK}$	–	–	$(V_{DD} \div 2) - 1$	V
$V_{IH}, OE$	Input HIGH Voltage, OE	2.0	–	$V_{DD}$	V
$V_{IL}, OE$	Input LOW Voltage, OE	–	–	0.8	V
ZO	Nominal Output Impedance	–	20	–	$\Omega$
CIN	Input Capacitance, OE	–	5.0	–	pF
IOS	Short Circuit Current	–	$\pm 80$	–	mA

# NB3L553

**Table 6. AC CHARACTERISTICS;  $V_{DD} = 2.5\text{ V} \pm 5\%$**  ( $V_{DD} = 2.375\text{ V}$  to  $2.625\text{ V}$ ,  $GND = 0\text{ V}$ ,  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$ ) (Note 3)

Symbol	Characteristic	Min	Typ	Max	Unit
$f_{in}$	Input Frequency	–	–	200	MHz
$t_r/t_f$	Output rise and fall times; 0.8 V to 2.0 V	–	1.0	1.5	ns
$t_{pd}$	Propagation Delay, CLK to $Q_n$ (Note 4)	2.2	3.0	5.0	ns
$t_{skew}$	Output-to-output skew; (Note 5)	–	35	50	ps
$t_{skew}$	Device-to-device skew, (Note 5)	–	–	500	ps

**AC CHARACTERISTICS;  $V_{DD} = 3.3\text{ V} \pm 5\%$**  ( $V_{DD} = 3.15\text{ V}$  to  $3.45\text{ V}$ ,  $GND = 0\text{ V}$ ,  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$ ) (Note 3)

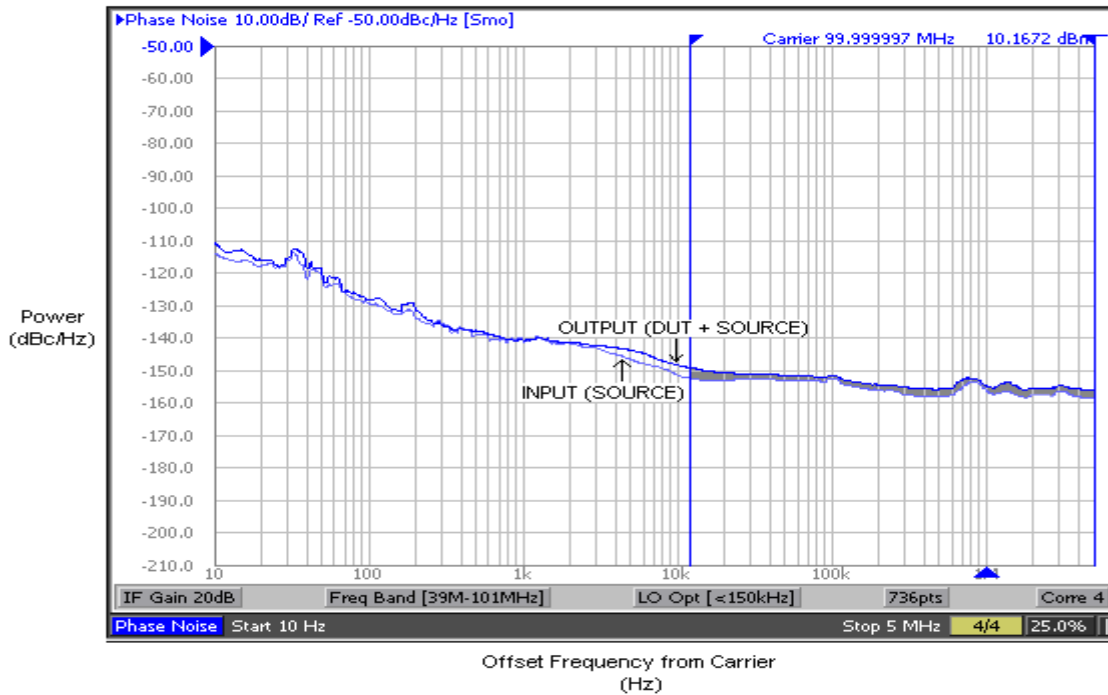
Symbol	Characteristic	Conditions	Min	Typ	Max	Unit
$f_{in}$	Input Frequency		–	–	200	MHz
$t_{jitter}(\phi)$	RMS Phase Jitter (Integrated 12 kHz – 20 MHz) (See Figures 2 and 3)	$f_{carrier} = 100\text{ MHz}$	–	18	–	fs
$t_r/t_f$	Output rise and fall times; 0.8 V to 2.0 V		–	0.6	1.0	ns
$t_{pd}$	Propagation Delay, CLK to $Q_n$ (Note 4)		2.0	2.4	4.0	ns
$t_{skew}$	Output-to-output skew; (Note 5)		–	35	50	ps
$t_{skew}$	Device-to-device skew, (Note 5)		–	–	500	ps

**AC CHARACTERISTICS;  $V_{DD} = 5.0\text{ V} \pm 5\%$**  ( $V_{DD} = 4.75\text{ V}$  to  $5.25\text{ V}$ ,  $GND = 0\text{ V}$ ,  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$ ) (Note 3)

Symbol	Characteristic	Min	Min	Typ	Max	Unit
$f_{in}$	Input Frequency		–	–	200	MHz
$t_{jitter}(\phi)$	RMS Phase Jitter (Integrated 12 kHz – 20 MHz) (See Figures 2 and 3)	$f_{carrier} = 100\text{ MHz}$	–	29	–	fs
$t_r/t_f$	Output rise and fall times; 0.8 V to 2.0 V		–	0.3	0.7	ns
$t_{pd}$	Propagation Delay, CLK to $Q_n$ (Note 4)		1.7	2.5	4.0	ns
$t_{skew}$	Output-to-output skew; (Note 5)		–	35	50	ps
$t_{skew}$	Device-to-device skew, (Note 5)		–	–	500	ps

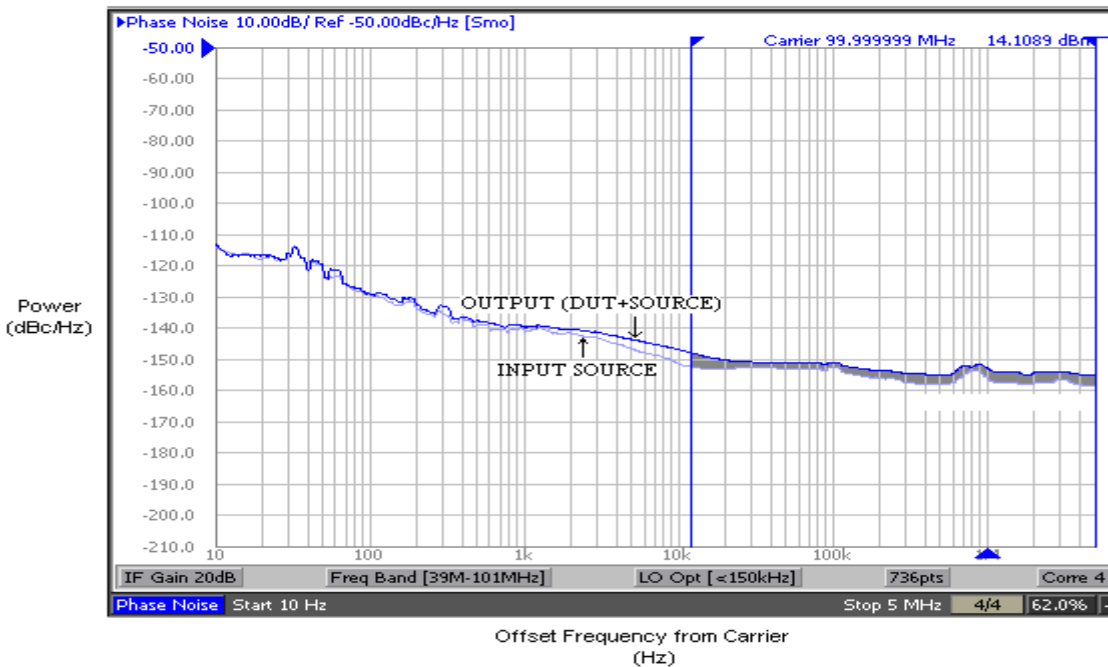
- Outputs loaded with external  $R_L = 33\ \Omega$  series resistor and  $C_L = 15\text{ pF}$  to GND. Duty cycle out = duty in. A  $0.01\ \mu\text{F}$  decoupling capacitor should be connected between  $V_{DD}$  and GND.
- Measured with rail-to-rail input clock
- Measured on rising edges at  $V_{DD} \div 2$  between any two outputs with equal loading.

## NB3L553



**Figure 2. Phase Noise Plot at 100 MHz at an Operating Voltage of 3.3 V, Room Temperature**

The above plot captured using Agilent E5052A shows Additive Phase Noise of the NB3L553 device measured with an input source generated by Agilent E8663B. The RMS phase jitter contributed by the device (integrated between 12 kHz to 20 MHz; as shown in the shaded area) is 18 fs (RMS Phase Jitter of the input source is 75.40 fs and Output (DUT+Source) is 93.16 fs).



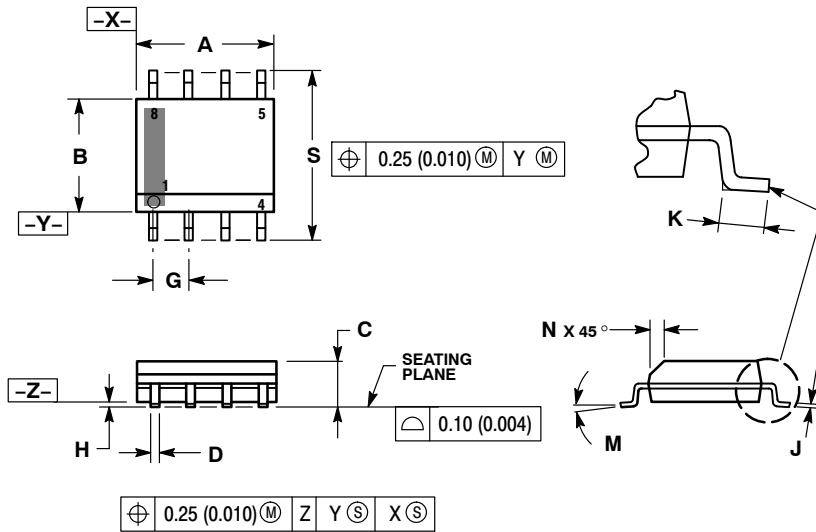
**Figure 3. Phase Noise Plot at 100 MHz at an Operating Voltage of 5 V, Room Temperature**

The above plot captured using Agilent E5052A shows Additive Phase Noise of the NB3L553 device measured with an input source generated by Agilent E8663B. The RMS phase jitter contributed by the device (integrated between 12 kHz to 20 MHz; as shown in the shaded area) is 29 fs (RMS Phase Jitter of the input source is 75.40 fs and Output (DUT+Source) is 103.85 fs).

# NB3L553

## PACKAGE DIMENSIONS

### SOIC-8 NB CASE 751-07 ISSUE AK

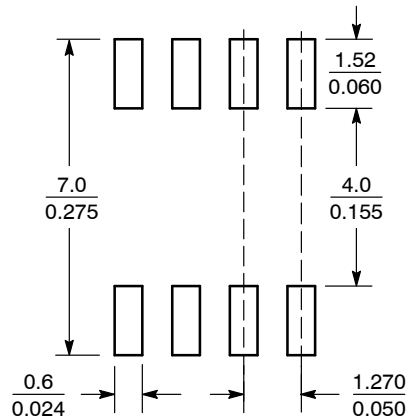


#### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0 °	8 °	0 °	8 °
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

#### SOLDERING FOOTPRINT\*



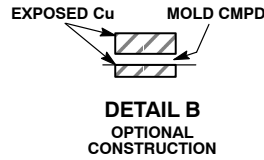
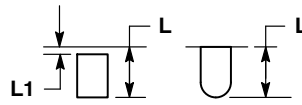
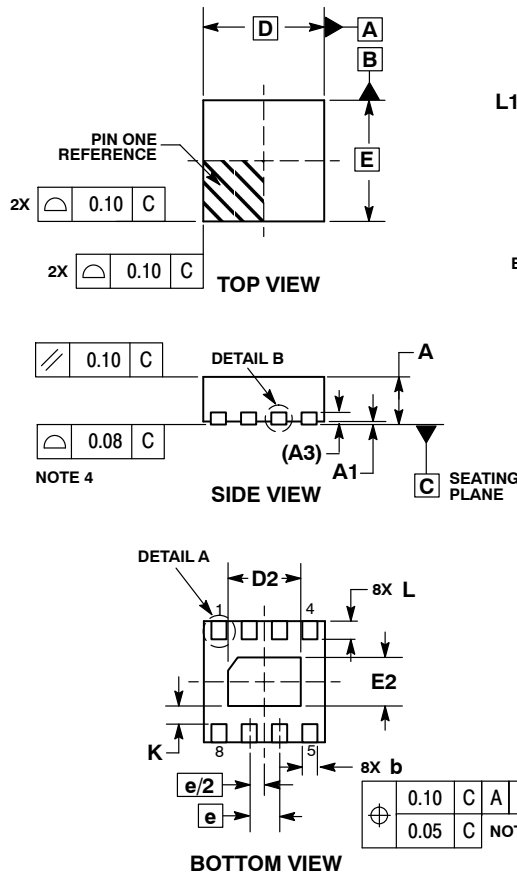
SCALE 6:1  $\left( \frac{\text{mm}}{\text{inches}} \right)$

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# NB3L553

## PACKAGE DIMENSIONS

DFN8 2x2, 0.5P  
CASE 506AA-01  
ISSUE E

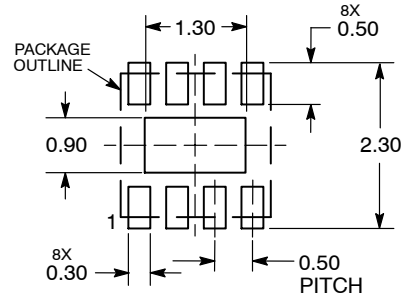


### NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

DIM	MILLIMETERS	
	MIN	MAX
A	0.80	1.00
A1	0.00	0.05
A3	0.20 REF	
b	0.20	0.30
D	2.00 BSC	
D2	1.10	1.30
E	2.00 BSC	
E2	0.70	0.90
e	0.50 BSC	
K	0.30 REF	
L	0.25	0.35
L1	---	0.10

### RECOMMENDED SOLDERING FOOTPRINT\*



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at [www.onsemi.com/site/pdf/Patent-Marketing.pdf](http://www.onsemi.com/site/pdf/Patent-Marketing.pdf). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor  
P.O. Box 5163, Denver, Colorado 80217 USA  
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada  
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada  
Email: [orderlit@onsemi.com](mailto:orderlit@onsemi.com)

N. American Technical Support: 800-282-9855 Toll Free  
USA/Canada

Europe, Middle East and Africa Technical Support:  
Phone: 421 33 790 2910

Japan Customer Focus Center  
Phone: 81-3-5817-1050

ON Semiconductor Website: [www.onsemi.com](http://www.onsemi.com)

Order Literature: <http://www.onsemi.com/orderlit>

For additional information, please contact your local  
Sales Representative



# AMEYA360

Components Supply Platform

Authorized Distribution Brand :



Website :

Welcome to visit [www.ameya360.com](http://www.ameya360.com)

Contact Us :

➤ Address :

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd  
Minhang District, Shanghai , China

➤ Sales :

Direct     +86 (21) 6401-6692  
Email      amall@ameya360.com  
QQ         800077892  
Skype      ameyasales1 ameyasales2

➤ Customer Service :

Email      service@ameya360.com

➤ Partnership :

Tel         +86 (21) 64016692-8333  
Email      mkt@ameya360.com